

OIP
 INFORMATION
 MAR 13 2005
 FBI
 PHOENIX

Group 21 Unit

[illegible][illegible]

RM	-	"40% Tunneling Magnetoresistance After Anneal at 380°C for Tunnel Junctions with Tunnel Oxide Interface Layers", by Shang et al., J. of Appl. Physics, Vol. 89, No. 11, June 1, 2001, pp. 6665-6667.
RM	-	"Oxygen as a Surfactant in the Growth of Giant Magnetoresistance Spin Valves", by W. F. Egelhoff, Jr. et al., J. of Appl. Physics, Vol. 82, No. 12, Dec. 15, 1997, pp. 6142-6151.

07/11/2006

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.